# UTC UNISONIC TECHNOLOGIES CO., LTD

# UTG50N120LND1-S

# Insulated Gate Bipolar Transistor

# 1200V TRENCH GATE FIELD-STOP IGBT

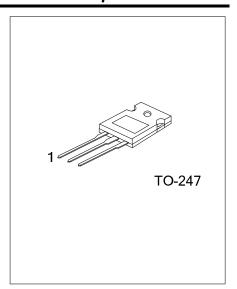
#### DESCRIPTION

The UTC UTG50N120LND1-S is an Trench Field-Stop Insulated Gate Bipolar Transistor, it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

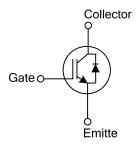
The UTC UTG50N120LND1-S is suitable for the resonant or soft switching applications.

#### **FEATURES**

- \* High switching speed
- \* High avalanche ruggedness
- \* Low saturation voltage: Vce(SAT).Typ.=2.0V @ Ic=50A, VGE=15V  $(T_C = 25^{\circ}C)$



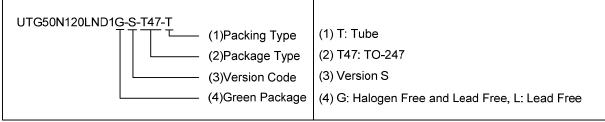
#### **SYMBOL**



# **ORDERING INFORMATION**

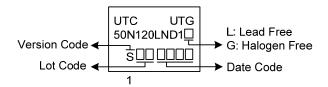
Ordering Number		Daalaaaa	Pin Assignment			Da aldin n	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG50N120LND1L-S-T47-T UTG50N120LND1G-S-T47-T		TO-247	G	С	Е	Tube	

Note: Pin Assignment: G: Gate C: Collector E: Emitter



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## **■** MARKING



## ■ **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub>=25°C, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage		V <sub>CES</sub>	1200	V
Gate-Emitter Voltage		\/	±20	V
Transient Gate-emitter voltage (tp < 5 ms)		$V_{GES}$	±25	V
Cantinuous Callester Current	T <sub>C</sub> =25°C	,	100	Α
Continuous Collector Current	T <sub>C</sub> =100°C	Ic	50	Α
Collector Current Pulsed (Note 1)		I <sub>CM</sub>	200	Α
Diada Farward Current	T <sub>C</sub> =25°C		60	Α
Diode Forward Current	T <sub>C</sub> =100°C	l <sub>F</sub>	30	Α
Power Dissipation (T <sub>C</sub> =25°C)		$P_{D}$	270	W
Operating Junction Temperature		$T_J$	-40 ~ +150	°C
Storage Temperature Range		T <sub>STG</sub>	-55 ~ <b>+</b> 150	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

#### **■ THERMAL DATA**

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θјс	0.46	°C/W

## ■ **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS			TYP	MAX	UNIT
Off Characteristics							
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>			1200			V
Collector Cut-Off Current	Ices	V <sub>CE</sub> =1200V, V <sub>GE</sub> =0V				5	μΑ
G-E Leakage Current	I <sub>GES</sub>	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V			±400	nA	
On Characteristics							
Gate to Emitter Threshold Voltage	V <sub>GE(TH)</sub>	Ic=250µA, VcE=VGE	4.5		7.5	V	
Collector to Emitter Saturation Voltage	V	I <sub>C</sub> =50A, V <sub>GE</sub> =15V	T <sub>C</sub> =25°C		2.0	2.5	V
Collector to Efficient Saturation Voltage	V <sub>CE(SAT)</sub>		T <sub>C</sub> =125°C		2.4		V
Dynamic Characteristics		T		ı		ı	
Input Capacitance	CIES				2.83		nF
Output Capacitance	C <sub>OES</sub>	V <sub>CE</sub> =25V, V <sub>GE</sub> =0V, f=1		132.4		pF	
Reverse Transfer Capacitance	C <sub>RES</sub>			42.3		pF	
Switching Characteristics					1		
Total Gate Charge	$Q_G$				127		nC
Gate-Emitter Charge	Q <sub>GE</sub>	$V_{CE}$ =600V, $I_{C}$ =50A, $V_{G}$		35		nC	
Gate-Collector Charge	$Q_GC$				56		nC
Turn-On Delay Time	t <sub>DON)</sub>	V <sub>CC</sub> =600V, I <sub>C</sub> =50A, R <sub>G</sub> =5Ω, V <sub>GE</sub> =0~15V, L=500μH			19		ns
Rise Time	t <sub>R</sub>				57		ns
Turn-Off Delay Time	t <sub>DOFF)</sub>				95		ns
Fall Time	t <sub>F</sub>				205		ns
Turn-On Switching Loss	Eon				4.23		mJ
Turn-Off Switching Loss	E <sub>OFF</sub>			3.14		mJ	
SOURCE- DRAIN DIODE RATINGS AND	CHARACTE	RISTICS					
Forward Voltage Drop	$V_{F}$	I <sub>F</sub> =50A				3.5	V
Reverse Recovery Time	t <sub>rr</sub>	I - 50 A 41/4t-400 A (v.S. ) / - 600 V			63.2		ns
Reverse Recovery Charge	Qrr	I <sub>F</sub> =50A, dI/dt=100A/μS, V <sub>CC</sub> =600V			1.7		μC

<sup>2.</sup> Pulse width limited by maximum junction temperature.

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